

PCN#20200324000.2 Qualification of an additional Fab site (RFAB), Die Revision, additional AT site (TI Malaysia) and BOM change for Select Devices Change Notification / Sample Request

Date: March 26, 2020 To: PREMIER FARNELL PCN

Dear Customer:

This is an announcement of change to a device that is currently offered by Texas Instruments. The details of this change are on the following pages.

Texas Instruments requires acknowledgement of receipt of this notification within **30** days of the date of this notice. Lack of acknowledgement of this notice within 30 days constitutes acceptance of the change. The proposed first ship date is indicated on page 3 of this notification, unless customer agreement has been reached on an earlier implementation of the change.

If samples or additional data are required, requests must be received within 30 days of acknowledgement as samples are not built ahead of the change. You may contact the PCN Manager or your local Field Sales Representative to acknowledge this PCN and request samples or additional data.

This notice does not change the end-of-life status of any product. Should product affected be on a previously issued product withdrawal/discontinuance notice, this notification does not extend the life of that product or change the life time buy offering/discontinuance plan.

For questions regarding this notice, contact your local Field Sales Representative or the PCN Team (<u>PCN ww admin team@list.ti.com</u>). For sample requests or sample related questions, contact your field sales representative.

Sincerely,

PCN Team SC Business Services

20200324000 Attachment: 1

Products Affected:

The devices listed on this page are a subset of the complete list of affected devices. According to our records, these are the devices that you have purchased within the past twenty-four (24) months. The corresponding customer part number is also listed, if available.

DEVICE

SN74HC132QPWRQ1

CUSTOMER PART NUMBER

null

Technical details of this Product Change follow on the next page(s).

PCN Number: 2020		200324000.2			PCN Date: Mar 2			Mar 26, 2020		
Title:Qualification of an ad Malaysia) and BOM c				itiona ange	al Fab site (RFA for Select Devi	B), Die F ces	Revisio	n, ad	ditic	onal AT site (TI
Customer	Contact:		PCI	N Ma	<u>nager</u>		Dept:			Quality Services
Proposed 1 st Ship Date:			Sept 26, 2020		Estimated Sample Availability:		e	Date provided at sample request.		
Change Type:										
Assembly Site				\boxtimes	Design				Wa	fer Bump Site
Assembly Process					Data Sheet				Wa	fer Bump Material
Assembly Materials					Part number c	hange			Wa	fer Bump Process
Mechanical Specification		ion		\boxtimes	Test Site			\boxtimes	Wa	fer Fab Site
Packing/Shipping/Labeling		beling			Test Process				Wa	fer Fab Materials
	Wafer Fab Process									
PCN Details										

Description of Change:

Texas Instruments is pleased to announce the qualification of an additional fab (RFAB), additional AT site (TI Malaysia) and BOM change for Select Devices.

Group 1 Device: Wafer Fab, Design, Additional A/T Site and BOM change

C	urrent Fab Site	e	Additional Fab Site		
Current Fab Site	Process	Wafer Diameter	Additional Fab Site	Process	Wafer Diameter
SFAB	HCMOS	150 mm	RFAB	LBC9	300 mm

The die was also changed as a result of the process change.

Additional A/T Site Material differences:

	Current Site	Additional Site
Assembly Site	TI Mexico	TI Malaysia
Wire Type	Au	Cu
Lead Finish	NiPdAu	NiPdAu, Roughened

Test coverage, insertions, conditions will remain consistent with current testing and verified with test MQ.

Group 2: Wafer Fab, Design, BOM change (Devices remains at current AT site)

C	urrent Fab Site	9	Additional Fab Site		
Current Fab Site	Process	Wafer Diameter	Additional Fab Site	Process	Wafer Diameter
SFAB	HCMOS	150 mm	RFAB	LBC9	300 mm

The die was also changed as a result of the process change.

BOM change:

	From	То
Mount Compound	4042500	4147858
Mold compound	4206193	4211471
Wire Type	Au	Cu
Lead Finish	NiPdAu (Non-Roughened)	NiPdAu (Roughened)

Reason for Change:

Improve Capacity

Antic	Anticipated impact on Form, Fit, Function, Quality or Reliability (positive / negative):					
	No Impact to the Material Declaration		Material Declarations or Product Content reports are driven from production data and will be available following the production release. Upon production release the revised reports can be obtained at the site link below <u>http://www.ti.com/quality/docs/materialcontentsearch.tsp</u>			

Changes to product identification resulting from this PCN:

Fab Site:

Current Chip Site	Chip Site Origin Code (20L)	Chip Site Country Code (21L)	Chip Site City
SFAB	GMT	USA	Sherman
New Chip Site	Chip Site Origin Code (20L)	Chip Site Country Code (21L)	Chip Site City
RFAB	RFB	USA	Richardson

Die Rev:

Current	New
Die Rev [2P]	Die Rev [2P]
E, F, G or H	В

Assembly Site:

Assembly Site	Assembly Site Origin (22L)	Assembly Country Code (23L)	Assembly City
TI Mexico	MEX	MEX	Aguascalientes
TI Malaysia	MLA	MYS	Kuala Lumpur

Sample product shipping label (not actual product label)

TEXAS INSTRUMENTS MADE IN: Malaysia 2DC: 20:	P G4		(1P) SN74LS07NSR (Q) 2000 (D) 0336
MSL 2 /260C/1 YEAR	SEAL DT	No. 2 States	(31T)LOT: 3959047MLA
MSL 1 /235C/UNLIM	03/29/04	1966-19-20-68	(4W) TKY(1T) 7523483SI2
OPT:			(P)
ITEM:	39		(21) REV: (V) 0033317
LBL: 5A (L)TO):1750		(22L) ASO: MLA (23L) ACO: MYS

Product Affected: Group 1

CD74HC08QM96Q1	SN74HC02QDRQ1	SN74HC132QDRQ1	SN74HC74QDRQ1
CD74HC125QM96G4Q1	SN74HC08QDRG4Q1	SN74HC14QDRG4Q1	SN74HC86IDRG4Q1
SN74HC00QDRG4Q1	SN74HC08QDRQ1	SN74HC14QDRQ1	SN74HC86QDRG4Q1
SN74HC00QDRQ1	SN74HC132QDRG4Q1	SN74HC74QDRG4Q1	

Product Affected: Group 2

CD74HC125QPWRG4Q1	SN74HC04IPWRG4Q1	SN74HC125IPWRG4Q1	SN74HC74QPWRQ1
CD74HC125QPWRQ1	SN74HC08IPWRG4Q1	SN74HC132QPWRG4Q1	SN74HC86IPWRG4Q1
SN74HC00QPWRG4Q1	SN74HC08IPWRQ1	SN74HC132QPWRQ1	SN74HC86QPWRG4Q1
SN74HC00QPWRQ1	SN74HC08QPWRG4Q1	SN74HC14QPWRG4Q1	SN74HC86QPWRQ1
SN74HC02QPWRG4Q1	SN74HC08QPWRQ1	SN74HC14QPWRQ1	
SN74HC02QPWRQ1	SN74HC10QPWRG4Q1	SN74HC74QPWRG4Q1	

Qualification Data Approved 14-Aug-2019

Product Attributes

Attributes	Qual Device: <u>SN74HCS74QDRQ1</u>	QBS Product Reference: <u>SN74HCS74QPWRQ1</u>
Automotive Grade Level	Grade 1	Grade 1
Operating Temp Range	-40 to +125 C	-40 to +125 C
Product Function	Logic	Logic
Wafer Fab Supplier	RFAB	RFAB
Die Revision	B1	B1
Assembly Site	MLA	MLA
Package Type	SOIC	TSSOP
Package Designator	D(SOIC)	PW
Ball/Lead Count	14	14

- QBS: Qual By Similarity - Qual Device SN74HCS74QDRQ1 is qualified at LEVEL1-260C

Qualification Results

Data Displayed as: Number of lots / Total sample size / Total failed

Туре	#	Test Spec	Min Lot Qty	SS/Lot	Test Name / Condition	Duration	Qual Device: <u>SN74HCS74QDRQ1</u>	QBS Product Reference: <u>SN74HCS74QPWRQ1</u>
	Test	Group A – A	ccelera	ated Envir	onment Stress Test	ts		
PC	A1	JEDEC J- STD-020 JESD22- A113	3	77	Preconditioning	Level 1- 260C	Sample Sizes as Required	Sample Sizes as Required
HAST	A2	JEDEC JESD22- A110	3	77	Biased HAST, 130C/85%RH	96 Hours	3/231/0	3/231/0
AC	A3	JEDEC JESD22- A102	3	77	Autoclave 121C	96 Hours	3/231/0	3/231/0
тс	A4	JEDEC JESD22- A104 and Appendix 3	3	77	Temperature Cycle, -65/150C	500 Cycles	3/231/0	3/231/0
PTC	A5	JEDEC JESD22- A105	1	45	Power Temperature Cycle	1000 Cycles	N/A	-
HTSL	A6	JEDEC JESD22- A103	1	45	High Temp Storage Bake 150C	1000 Hours	3/135/0	3/135/0
	Test	Group B – A	ccelera	ated Lifeti	me Simulation Test	s		
HTOL	B1	JEDEC JESD22- A108	3	77	Life Test, 150C	600 Hours	1/77/0	3/231/0
ELFR	B2	AEC Q100-008	3	800	Early Life Failure Rate, 125C	48 Hours	-	3/2400/0
EDR	B3	AEC Q100-005	3	77	NVM Endurance, Data Retention, and Operational Life	-	N/A	-
	Те	st Group C –	Packa	ge Assen	nbly Integrity Tests			
WBS	C1	AEC Q100-001	1	30	Wire Bond Shear (Cpk>1.67)	Minimum of 5 devices, 30 wires Cpk>1.67	3/90/0	3/90/0

Туре	#	Test Spec	Min Lot Qty	SS/Lot	Test Name / Condition	Duration	Qual Device: <u>SN74HCS74QDRQ1</u>	QBS Product Reference: <u>SN74HCS74QPWRQ1</u>
WBP	C2	MIL- STD883 Method 2011	1	30	Wire Bond Pull (Cpk>1.67)	Minimum of 5 devices, 30 wires Cpk>1.67	3/90/0	3/90/0
SD	C3	JEDEC JESD22- B102	1	15	Pb Free Surface Mount Solderability	8 Hours Steam Age	3/45/0	3/45/0
PD	C4	JEDEC JESD22- B100 and B108	3	10	Physical Dimensions (Cpk>1.67)	Cpk>1.67	3/90/0	3/90/0
LI	C6	JEDEC JESD22- B105	1	50	Lead Integrity	-	-	-
	Т	est Group D	– Die F	abricatio	n Reliability Tests			
EM	D1	JESD61	-	-	Electromigration	-	Completed Per Process Technology Requirements	-
TDDB	D2	JESD35	-	-	Time Dependant Dielectric Breakdown	-	Completed Per Process Technology Requirements	-
HCI	D3	JESD60 & 28	-	-	Hot Injection Carrier	-	Completed Per Process Technology Requirements	-
NBTI	D4	-	-	-	Negative Bias Temperature Instability	-	Completed Per Process Technology Requirements	-
SM	D5	-	-	-	Stress Migration	-	Completed Per Process Technology Requirements	-
	1	Test Group	E – Ele	ectrical Ve	rification Tests			
HBM	E2	AEC Q100-002	1	3	ESD - HBM - Q100	7000V	-	1/3/0
HBM	E2	AEC Q100-002	1	3	ESD - HBM - Q100	8000 V	1/3/0	-
CDM	E3	AEC Q100-011	1	3	ESD - CDM - Q100	1500V	-	1/3/0
CDM	E3	AEC Q100-011	1	3	ESD - CDM - Q100	2000 V	1/3/0	-
LU	E4	AEC Q100-004	1	6	Latch-up	Per AEC Q100-004	1/6/0	1/6/0
ED	E5	AEC Q100-009	3	30	Electrical Distributions	Cpk>1.67 Room, hot, and cold test	3/90/0	3/90/0

A1 (PC): Preconditioning:

Performed for THB, Biased HAST, AC, uHAST, TC & PTC samples, as applicable. Ambient Operating Temperature by Automotive Grade Level:

Grade 0 (or E): -40°C to +150°C Grade 1 (or Q): -40°C to +125°C Grade 2 (or T): -40°C to +105°C Grade 3 (or I): -40°C to +85°C

E1 (TEST): Electrical test temperatures of Qual samples (High temperature according to Grade level): Room/Hot/Cold : HTOL, ED Room/Hot : THB / HAST, TC / PTC, HTSL, ELFR, ESD & LU Room : AC/uHAST

Green/Pb-free Status: Qualified Pb-Free(SMT) and Green

Texas Instruments, Inc.

Qualification Data Approved on 06/19/2019

Product Attributes

Attributes	Qual Device: <u>SN74HCS74QPWRQ1</u>
Automotive Grade Level	Grade 1
Operating Temp Range	-40 to +125 C
Product Function	Logic
Wafer Fab Supplier	RFAB
Die Revision	B1
Assembly Site	MLA
Package Type	TSSOP
Package Designator	PW
Ball/Lead Count	14

- QBS: Qual By Similarity

- Qual Device SN74HCS74QPWRQ1 is qualified at LEVEL1-260C

Qualification Results

Data Displayed as: Number of lots / Total sample size / Total failed

Туре	#	Test Spec	Min Lot Qty	SS/Lot	Test Name / Condition	Duration	Qual Device: <u>SN74HCS74QPWRQ1</u>
PC	A1	JEDEC J-STD- 020 JESD22- A113	3	77	Preconditioning	Level 1-260C	3/828/0
HAST	A2	JEDEC JESD22-A110	3	77	Biased HAST, 130C/85%RH	96 Hours	3/231/0
AC	A3	JEDEC JESD22-A102	3	77	Autoclave 121C	96 Hours	3/231/0
тс	A4	JEDEC JESD22-A104 and Appendix 3	3	77	Temperature Cycle, - 65/150C	500 Cycles	3/231/0
PTC	A5	JEDEC JESD22-A105	1	45	Power Temperature Cycle	1000 Cycles	N/A
HTSL	A6	JEDEC JESD22-A103	1	45	High Temp Storage Bake 150C	1000 Hours	3/135/0
HTOL	B1	JEDEC JESD22-A108	3	77	Life Test, 150C	300 Hours	3/231/0
ELFR	B2	AEC Q100-008	3	800	Early Life Failure Rate, 125C	48 Hours	3/2400/0
EDR	В3	AEC Q100-005	3	77	NVM Endurance, Data Retention, and Operational Life	-	N/A
		Test Group	C – Pac	kage Asse	embly Integrity Tests		
WBS	C1	AEC Q100-001	1	30	Wire Bond Shear (Cpk>1.67)	-	3/90/0
WBP	C2	MIL-STD883 Method 2011	1	30	Wire Bond Pull (Cpk>1.67)	-	3/90/0
SD	C3	JEDEC JESD22-B102	1	15	Pb Free Surface Mount Solderability	8 Hours Steam Age	3/45/0
SD	C3	JEDEC JESD22-B102	1	15	Surface Mount Solderability >95% Lead Coverage	-	3/45/0
PD	C4	JEDEC JESD22-B100 and B108	3	10	Physical Dimensions (Cpk>1.67)	-	3/90/0

Texas Instruments, Inc.

Туре	#	Test Spec	Min Lot Qty	SS/Lot	Test Name / Condition	Duration	Qual Device: <u>SN74HCS74QPWRQ1</u>
		Test Group	o D – Die	e Fabricati	ion Reliability Tests		
EM	D1	JESD61	-	-	Electromigration	-	Completed Per Process Technology Requirements
TDDB	D2	JESD35	-	-	Time Dependant Dielectric Breakdown	-	Completed Per Process Technology Requirements
HCI	D3	JESD60 & 28	-	-	Hot Injection Carrier	-	Completed Per Process Technology Requirements
NBTI	D4	-	-	-	Negative Bias Temperature Instability	-	Completed Per Process Technology Requirements
SM	D5	-	-	-	Stress Migration	-	Completed Per Process Technology Requirements
Test Group E – Electrical Verification Tests							
HBM	E2	AEC Q100-002	1	3	ESD - HBM - Q100	7000V	1/3/0
CDM	E3	AEC Q100-011	1	3	ESD - CDM - Q100	1500V	1/3/0
LU	E4	AEC Q100-004	1	6	Latch-up	Per AEC Q100-004	1/6/0
ED	E5	AEC Q100-009	3	30	Electrical Distributions	Cpk>1.67 Room, hot, and cold test	3/90/0

A1 (PC): Preconditioning:

Performed for THB, Biased HAST, AC, uHAST, TC & PTC samples, as applicable.

Ambient Operating Temperature by Automotive Grade Level:

Grade 0 (or E): -40°C to +150°C

Grade 1 (or Q): -40°C to +125°C

Grade 2 (or T): -40°C to +105°C

Grade 3 (or I) : -40°C to +85°C

E1 (TEST): Electrical test temperatures of Qual samples (High temperature according to Grade level): Room/Hot/Cold : HTOL, ED Room/Hot : THB / HAST, TC / PTC, HTSL, ELFR, ESD & LU Room : AC/uHAST

Green/Pb-free Status: Qualified Pb-Free(SMT) and Green

For questions regarding this notice, e-mails can be sent to the regional contacts shown below, or you can contact your local Field Sales Representative.

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